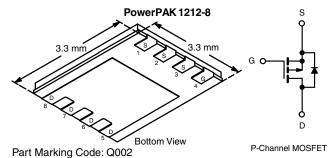
## SQ7415EN



**Vishay Siliconix** 

# Automotive P-Channel 60 V (D-S) 175 °C MOSFET

| PRODUCT SUMMARY                           |        |  |  |  |
|---|--------|--|--|--|
| V <sub>DS</sub> (V)                       | - 60   |  |  |  |
| $R_{DS(on)}(\Omega)$ at $V_{GS}$ = - 10 V | 0.065  |  |  |  |
| $R_{DS(on)}(\Omega)$ at $V_{GS} = -4.5 V$ | 0.110  |  |  |  |
| I <sub>D</sub> (A)                        | - 5.7  |  |  |  |
| Configuration                             | Single |  |  |  |



#### **FEATURES**

- TrenchFET<sup>®</sup> Power MOSFET
- PowerPAK<sup>®</sup> Package - Low Thermal Resistance, R<sub>thJC</sub>
  - Low 1.07 mm Profile
- · Fast Switching
- AEC-Q101 Qualified
- 100 % R<sub>q</sub> Tested
- · Material categorization: For definitions of compliance please see www.vishay.com/doc?99912



RoHS COMPLIANT

| ORDERING INFORMATION |                 |  |
|----------------------|-----------------|--|
| Package              | PowerPAK 1212-8 |  |
| Lead (Pb)-free       | SQ7415EN-T1-E3  |  |

| <b>ABSOLUTE MAXIMUM RATINGS</b> ( $T_A = 25$ °C, unless otherwise noted) |                        |                                   |               |               |      |  |
|--|------------------------|-----------------------------------|---------------|---------------|------|--|
| PARAMETER  |                        | SYMBOL                            | 10 s          | STEADY STATE  | UNIT |  |
| Drain-Source Voltage   |                        | V <sub>DS</sub>                   | - 60          | - 60          | V    |  |
| Gate-Source Voltage  |                        | V <sub>GS</sub>                   | ± 20          | ± 20          |      |  |
| Continuous Drain Current <sup>a</sup>                                    | T <sub>A</sub> = 25 °C | - I <sub>D</sub>                  | - 5.7         | - 3.6         | ^    |  |
|  | T <sub>A</sub> = 70 °C |                                   | - 4.6         | - 2.9         |      |  |
| Continuous Source Current (Diode Conduction) <sup>a</sup>                |                        | I <sub>S</sub>                    | - 3.2         | - 1.3         | A    |  |
| Pulsed Drain Current <sup>b</sup>  |                        | I <sub>DM</sub>                   | - 30          | - 30          |      |  |
| Maximum Power Dissipation <sup>b</sup>                                   | T <sub>A</sub> = 25 °C | - P <sub>D</sub>                  | 3.8           | 1.5           | W    |  |
|  | T <sub>A</sub> = 70 °C |                                   | 2             | 0.8           |      |  |
| Operating Junction and Storage Temperature Range                         |                        | T <sub>J</sub> , T <sub>stg</sub> | - 55 to + 175 | - 55 to + 175 | •••  |  |
| Soldering Recommendations (Peak Temperature) <sup>d, e</sup>             |                        |                                   | 260           | 260           | °C   |  |

| THERMAL RESISTANCE RATINGS |                        |                   |         |         |      |
|----------------------------|------------------------|-------------------|---------|---------|------|
| PARAMETER                  |                        | SYMBOL            | TYPICAL | MAXIMUM | UNIT |
| Junction-to-Ambient        |                        | R <sub>thJA</sub> | 26      | 33      | °C/W |
|                            | PCB Mount <sup>c</sup> |                   | 65      | 81      |      |
| Junction-to-Case (Drain)   |                        | R <sub>thJC</sub> | 1.9     | 2.4     |      |

Notes

a. Package limited.

b. Pulse test; pulse width  $\leq$  300 µs, duty cycle  $\leq$  2 %.

c. When mounted on 1" square PCB (FR-4 material).

d. See solder profile (www.vishay.com/doc?73257). The PowerPAK 1212-8 is a leadless package. The end of the lead terminal is exposed copper (not plated) as a result of the singulation process in manufacturing. A solder fillet at the exposed copper tip cannot be guaranteed and is not required to ensure adequate bottom side solder interconnection.

e. Rework conditions: manual soldering with a soldering iron is not recommended for leadless components.

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| PARAMETER                                     | SYMBOL                | TEST CONDITIONS  | MIN.  | TYP.  | MAX.    | UNIT |  |  |
|---|-----------------------|--|-------|-------|---------|------|--|--|
| Static  |                       |  | •     |       |         | •    |  |  |
| Drain-Source Breakdown Voltage                | V <sub>DS</sub>       | $V_{GS} = 0 \text{ V}, \text{ I}_{D} = -250 \mu\text{A}$                                     | - 60  | -     | -       | v    |  |  |
| Gate-Source Threshold Voltage                 | V <sub>GS(th)</sub>   | $V_{DS} = V_{GS}, I_D = -250 \ \mu A$  | - 1.5 | -     | - 3     |      |  |  |
| Gate-Source Leakage                           | I <sub>GSS</sub>      | $V_{DS} = 0 V, V_{GS} = \pm 20 V$  | -     | -     | ± 100   | nA   |  |  |
| Zero Gate Voltage Drain Current               |                       | $V_{GS} = 0 V, V_{DS} = -60 V$   | -     | -     | - 1     | μA   |  |  |
|   | I <sub>DSS</sub>      | $V_{GS} = 0 \text{ V}, \text{ V}_{DS} = -60 \text{ V}, \text{ T}_{J} = 125 ^{\circ}\text{C}$ | -     | -     | - 5     |      |  |  |
|   |                       | $V_{GS} = 0 \text{ V}, \text{ V}_{DS} = -60 \text{ V}, \text{ T}_{J} = 175 ^{\circ}\text{C}$ | -     | -     | - 150   |      |  |  |
| On-State Drain Current <sup>a</sup>           | I <sub>D(on)</sub>    | $V_{GS}$ = - 10 V, $V_{DS}$ $\leq$ - 5 V   | - 20  | -     | -       | Α    |  |  |
| Drain-Source On-State Resistance <sup>a</sup> |                       | V <sub>GS</sub> = - 10 V, I <sub>D</sub> = - 5.7 A   | -     | 0.054 | 0.065   | Ω    |  |  |
|   | Р                     | $V_{GS} = -4.5 \text{ V}, \text{ I}_{D} = -4.4 \text{ A}$                                    | -     | 0.090 | 0.110   |      |  |  |
|   | R <sub>DS(on)</sub>   | $V_{GS}$ = - 10 V, I <sub>D</sub> = - 5.7 A, T <sub>j</sub> = 125 °C                         | -     | -     | - 0.104 |      |  |  |
|   |                       | V <sub>GS</sub> = - 10 V, I <sub>D</sub> = - 5.7 A, T <sub>j</sub> = 175 °C                  | -     | -     | 0.127   |      |  |  |
| Forward Transconductance <sup>a</sup>         | 9 <sub>fs</sub>       | V <sub>DS</sub> = - 15 V, I <sub>D</sub> = - 5.7 A   | 11    | -     | -       | S    |  |  |
| Dynamic <sup>b</sup>                          |                       |  |       |       |         |      |  |  |
| Input Capacitance                             | C <sub>iss</sub>      |  | -     | 940   | 1175    | pF   |  |  |
| Output Capacitance                            | C <sub>oss</sub>      | $V_{GS} = 0 V, V_{DS} = 25 V, f = 1 MHz$   | -     | 151   | 189     |      |  |  |
| Reverse Transfer Capacitance                  | C <sub>rss</sub>      |  | -     | 54    | 68      |      |  |  |
| Total Gate Charge <sup>c</sup>                | Qg                    |  | -     | 15    | 25      | nC   |  |  |
| Gate-Source Charge <sup>c</sup>               | Q <sub>gs</sub>       | $V_{GS}$ = - 10 V, $V_{DS}$ = - 30 V, $I_D$ = - 5.7 A  | -     | 4     | -       |      |  |  |
| Gate-Drain Charge <sup>c</sup>                | Q <sub>gd</sub>       |  | -     | 3.2   | -       |      |  |  |
| Gate Resistance                               | R <sub>g</sub>        | f = 1 MHz  | 0.8   | 1.8   | 2.8     | Ω    |  |  |
| Turn-On Delay Time <sup>c</sup>               | t <sub>d(on)</sub>    | $V_{DD} = -30 \text{ V}, \text{ R}_{\text{L}} = 30 \Omega$                                   | -     | 12    | 20      |      |  |  |
| Rise Time <sup>c</sup>                        | t <sub>r</sub>        |  | -     | 12    | 20      |      |  |  |
| Turn-Off Delay Time <sup>c</sup>              | t <sub>d(off)</sub>   |  | -     | 22    | 35      | ns   |  |  |
| Fall Time <sup>c</sup>                        | t <sub>f</sub>        |  | -     | 16    | 25      |      |  |  |
| Source-Drain Diode Ratings and Char           | acteristics $T_C = 2$ | 25 °C <sup>b</sup>   |       |       |         |      |  |  |
| Pulsed Current <sup>a</sup>                   | I <sub>SM</sub>       |  | -     | -     | - 30    | Α    |  |  |
| Forward Voltage                               | V <sub>SD</sub>       | I <sub>F</sub> = 85 A, V <sub>GS</sub> = 0 V   | -     | -     | - 1.2   | V    |  |  |
| Reverse Recovery Time                         | t <sub>rr</sub>       | I <sub>F</sub> = 3.2 A, dl/dt = 100 A/μs   | -     | 45    | 90      | ns   |  |  |

Notes

a. Pulse test; pulse width  $\leq 300~\mu s,~duty~cycle \leq 2~\%.$ 

b. Guaranteed by design, not subject to production testing.

c. Independent of operating temperature.

Stresses beyond those listed under "Absolute Maximum Ratings" may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated in the operational sections of the specifications is not implied. Exposure to absolute maximum rating conditions for extended periods may affect device reliability.

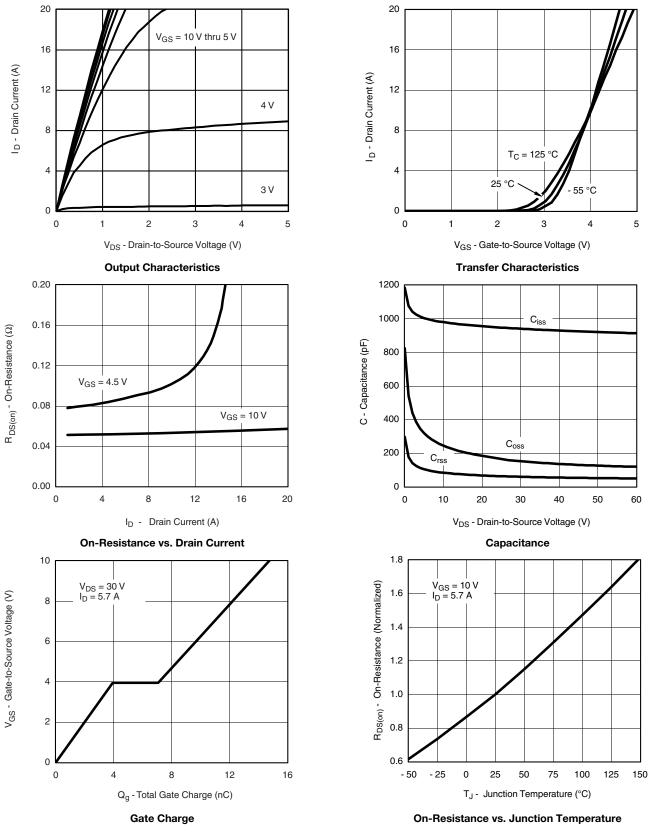
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### **TYPICAL CHARACTERISTICS** (T<sub>A</sub> = 25 °C, unless otherwise noted)



S13-1462 Rev. E, 01-Jul-13

3

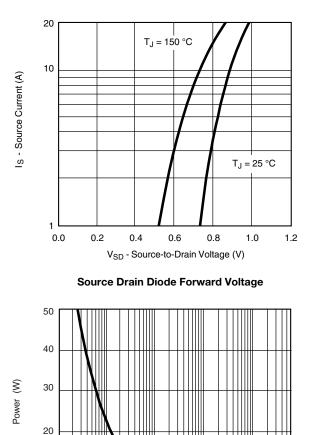
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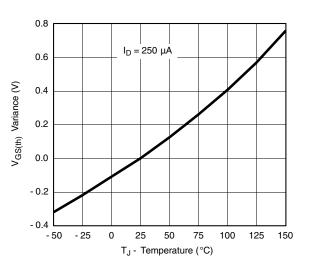


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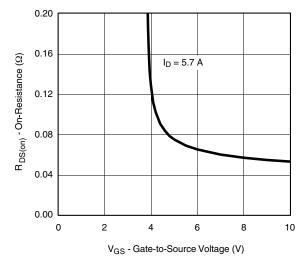
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### **TYPICAL CHARACTERISTICS** (T<sub>A</sub> = 25 °C, unless otherwise noted)





**Threshold Voltage** 



**On-Resistance vs. Gate-to-Source Voltage** 

10

0

0.01

0.1

1

Time (s)

Single Pulse Power, Junction-to-Ambient

10

100

600

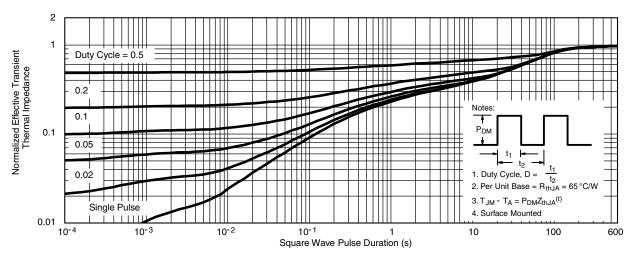
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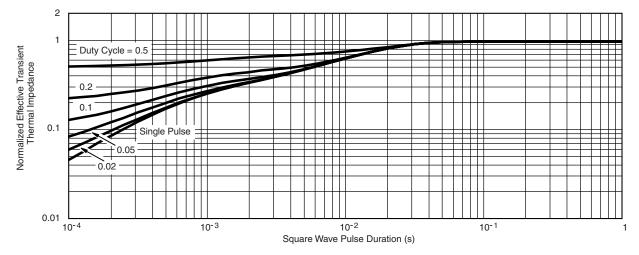


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#### THERMAL RATINGS (T<sub>A</sub> = 25 °C, unless otherwise noted)



Normalized Thermal Transient Impedance, Junction-to-Ambient



Normalized Thermal Transient Impedance, Junction-to-Case

#### Note

The characteristics shown in the two graphs

- Normalized Transient Thermal Impedance Junction-to-Ambient (25 °C)

- Normalized Transient Thermal Impedance Junction-to-Case (25 °C)

are given for general guidelines only to enable the user to get a "ball park" indication of part capabilities. The data are extracted from single pulse transient thermal impedance characteristics which are developed from empirical measurements. The latter is valid for the part mounted on printed circuit board - FR4, size 1" x 1" x 0.062", double sided with 2 oz. copper, 100 % on both sides. The part capabilities can widely vary depending on actual application parameters and operating conditions.

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